

DMP3056LDM P-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

Features

- Low R_{DS(ON)}:
 - $45m\Omega @V_{GS} = -10V$
 - 65mΩ @V_{GS} = -4.5V
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- "Green" Device (Note 4)

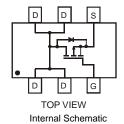
Mechanical Data

- Case: SOT-26
- Case Material Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking Information: See Page 4
- Ordering Information: See page 4
- Weight: 0.008 grams (approximate)

SOT-26



TOP VIEW



Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage		V _{DSS}	-30	V
Gate-Source Voltage		V _{GSS}	±20	V
Drain Current (Note 1) Continuous (V _{GS} = -10V)	T _A = 25°C T _A = 70°C	ID	-5 -4.2	A
Pulsed Drain Current (Note 2)		I _{DM}	-13	A

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 1)	PD	1.25	W
Thermal Resistance, Junction to Ambient (Note 1); Steady-State	R _{0JA}	100	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	۵°

Notes: 1. Device mounted on 1"x1", FR-4 PC board on 0.1in.² pads on 2 oz. Copper pads and test pulse width t ≤10s. 2. Repetitive Rating, pulse width limited by junction temperature.

3. No purposefully added lead.

4. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com/products/lead_free/index.php.

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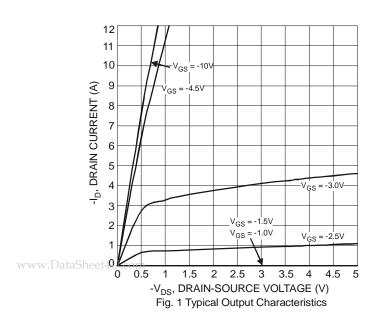


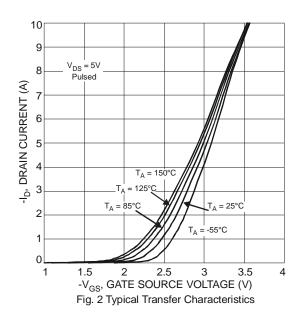
Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
STATIC PARAMETERS							
Drain-Source Breakdown Voltage	BV _{DSS}	-30	_		V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current $T_J = 25$	5°C I _{DSS}	_	_	-1	μΑ	$V_{GS} = 0V, V_{DS} = -30V$	
Gate-Body Leakage Current	IGSS	_	_	±100 ±800	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$ $V_{GS} = \pm 25V, V_{DS} = 0V$	
Gate Threshold Voltage	V _{GS(th)}	-1.0		-2.1	V	$V_{GS} = V_{DS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance (Note 5)	R _{DS (ON)}	_		45 65	mΩ	$V_{GS} = -10V, I_D = -5A$ $V_{GS} = -4.5V, I_D = -4.2A$	
Forward Transconductance (Note 5)	g fs	_	8	_	S	V _{DS} = -10V, I _D = -4.3A	
Diode Forward Voltage (Note 5)	V _{SD}	_	_	-1.2	V	$V_{GS} = 0V, I_{S} = -1.7A$	
DYNAMIC PARAMETERS (Note 6)	-					·	
Input Capacitance	Ciss		722		pF		
Output Capacitance	Coss		114		pF	−V _{GS} = 0V, V _{DS} = -25V, −f = 1.0MHz	
Reverse Transfer Capacitance	Crss	_	92	_	pF	1 = 1.000112	
Gate Resistance	R _G	_	3.3	_	Ω	$V_{DS} = 0V, V_{GS} = 0V$ f = 1.0MHz	
SWITCHING CHARACTERISTICS						·	
Total Gate Charge	Q_{G}	—	10.1	—	nC	$V_{DS} = -15V, V_{GS} = -4.5V,$ $I_{D} = -6A$	
-	Q_{G}	_	21.1			V _{DS} = -15V, V _{GS} = -10V, I _D = -6A	
Gate-Source Charge	Q_{GS}	_	2.8		nC		
Gate-Drain Charge		_	3.2			ID = -OA	
Gate Resistance	Rg	_	13.15		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Turn-On Delay Time		_	6.4				
Rise Time	tr	_	5.3	_	ns	$V_{DS} = -15V, V_{GS} = -10V,$ $I_D = -1A, R_G = 6.0\Omega$	
Turn-Off Delay Time	t _{d(off)}	_	26.5		115		
Fall Time			14.7]		

Notes:

5. Test pulse width t = 300μ s. 6. Guaranteed by design. Not subject to production testing.









125 150

 $V_{GS} = -10V$ $I_D = -4.3A$

75

f = 1MHz

Cis

20

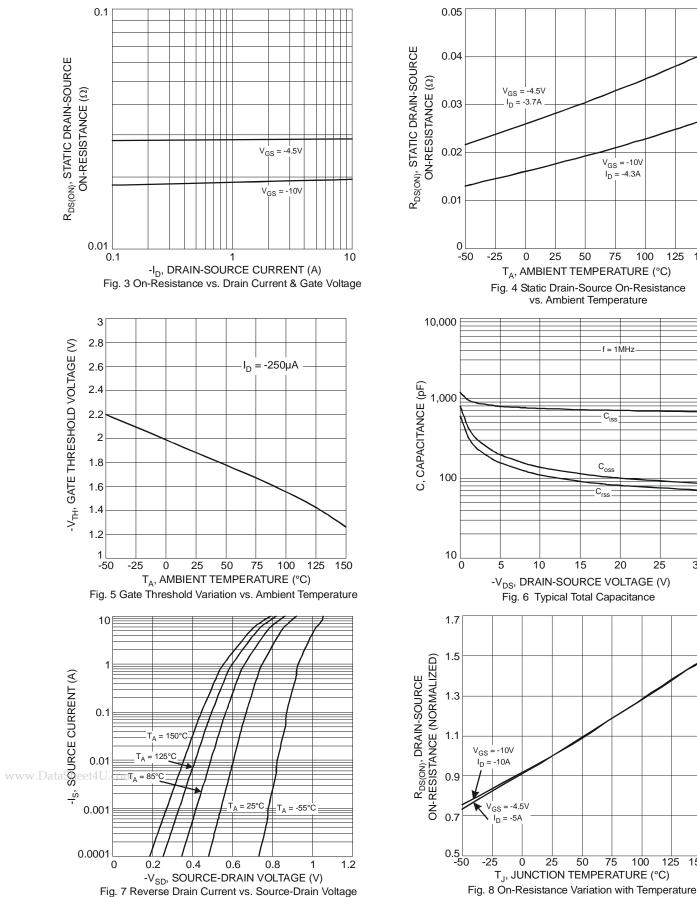
75

100

25

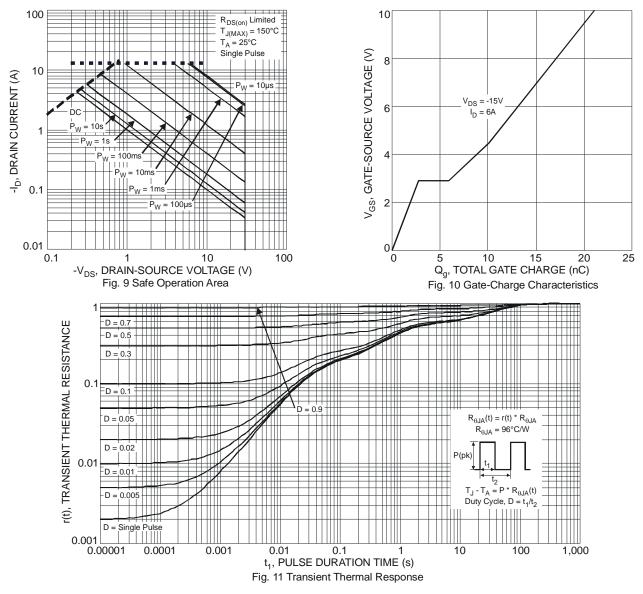
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100



DMP3056LDM Document number: DS31449 Rev. 8 - 2 125 150

DMP3056LDM

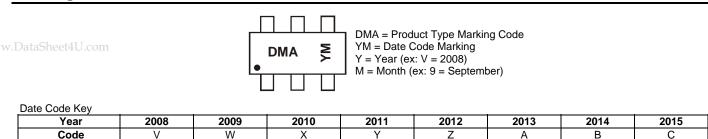


Ordering Information (Note 7)

Part Number	Case	Packaging
DMP3056LDM-7	SOT-26	3000/Tape & Reel

Notes: 7. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

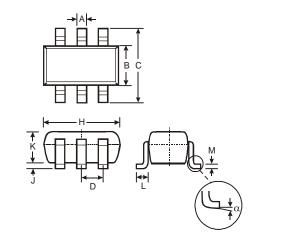
Marking Information



Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

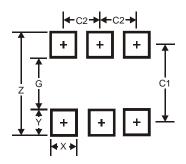


Package Outline Dimensions



SOT-26						
Dim	Min	Max	Тур			
Α	0.35	0.50	0.38			
в	1.50	1.70	1.60			
С	2.70	3.00	2.80			
D		_	0.95			
Н	2.90	3.10	3.00			
J	0.013	0.10	0.05			
Κ	1.00	1.30	1.10			
L	0.35	0.55	0.40			
Μ	0.10	0.20	0.15			
α	0°	8°				
All Dimensions in mm						

Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
Х	0.55
Y	0.80
C1	2.40
C2	0.95

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